IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

PATENT APPLICATION

FISCHIONE ET AL.

METHOD AND APPARATUS FOR

Serial No.: To be assigned

PREPARING SPECIMENS FOR

MICROSCOPY

Filed August 1, 2003

INFORMATION DISCLOSURE STATEMENT

Pittsburgh, Pennsylvania 15222

August 1, 2003

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. §§1.51, 1.56, 1.97 and 1.98, a copy of the art identified on attached form PTO-1449 is enclosed herewith as a citation in connection with the captioned application. The applicants hereby request the Examiner to review and make an independent evaluation of the art. A copy of each reference is provided.

Express Mail mailing label number:
EV 068576799US
Date of Deposit:
August 1, 2003 I hereby certify that his paper or fee is being deposited with the United States Postal Service "Express Mail Post Office to Addressee" service under 37 CFR 1.10 on the date indicated above and is addressed to the Assistant Commissioner for Patents, Washington, D.C. 20231. Barry I. Friedman, Esq. Name of Person Signing
Signature

Koch, et al. United States Patent No. 3,958,124

Fischione, United States Patent No. 5,633,502

Subramanian, et al., United States Patent No. 6,190,062

Model 682, Precision Etching Coating System (PECS), Gatan Inc., 2001

Ion Beam Sputter Deposition and Etching System IBS/e, downloaded from the Internet at http://www.southbaytech.com/cgi-bin/homepage/products/view_product.cfm.

Recent Advances in Broad Ion Beam Techniques/Instrumentation for SEM Specimen Preparation of Semiconductors, Alani R., Mitro, R.J., Hauffe, W., Proceeding from the 25th International Symposium for Testing and Failure Analysis, November 1999.

No fee is believed to be required in connection with the filing of this Information

Disclosure Statement because it is being submitted prior to the mailing of a first office action on the merits in the above-captioned application.

Applicants believe that their METHOD AND APPARATUS FOR
PREPARING SPECIMENS FOR MICROSCOPY as described and claimed in the present
application is neither taught nor suggested by this art. Accordingly, applicants' invention is
believed to be patentable over these references.

Respectfully submitted,

METZ LEWIS LLC

Barry I. Friedman, Reg. No. 33,695

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Pittsburgh, Pennsylvania 15222

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Form PTO-A820 (also form PTO-1449) P09C/REV03

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